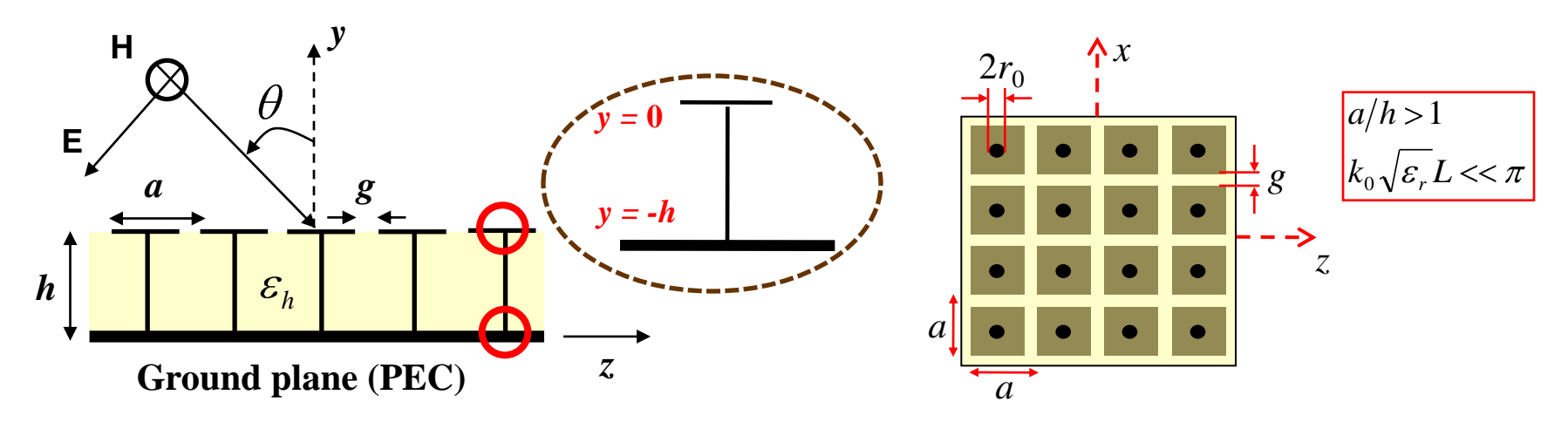


# Reflection Properties of Mushroom-Type Surfaces With Loaded Vias

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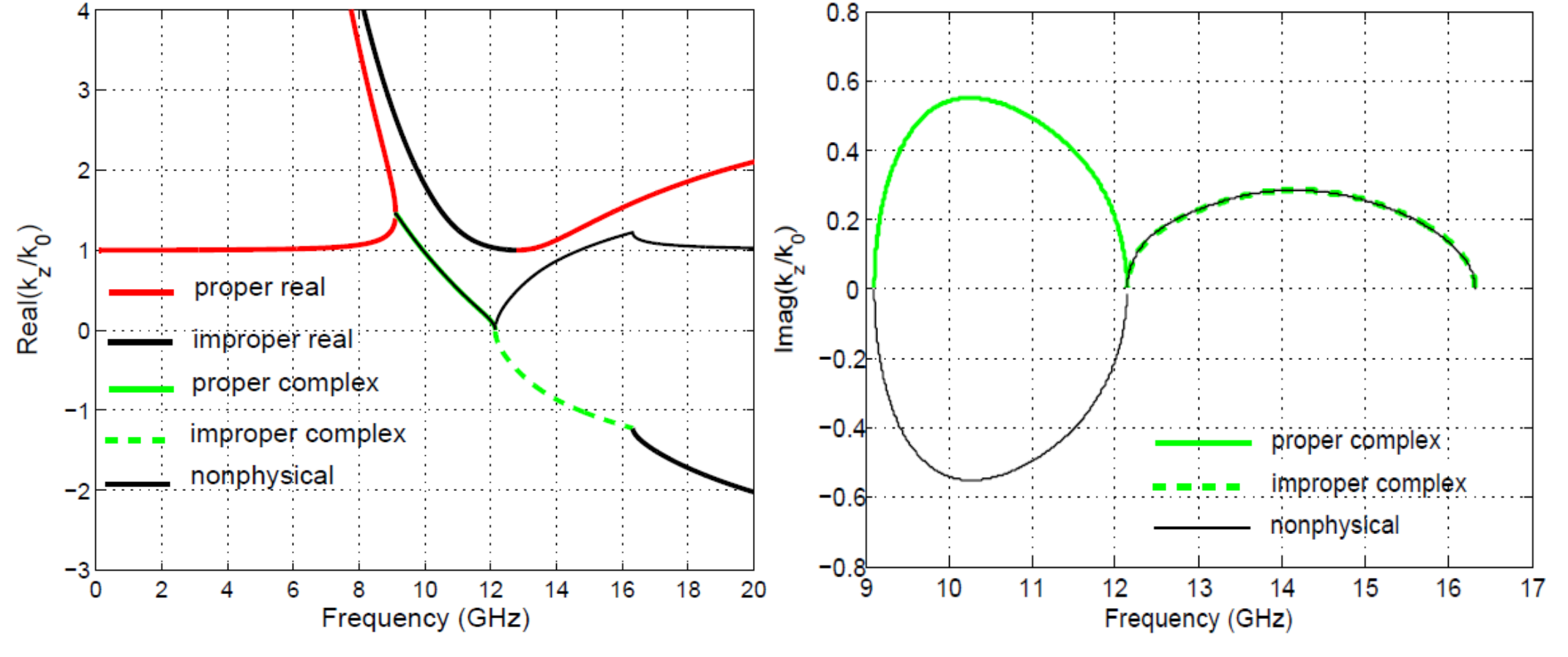
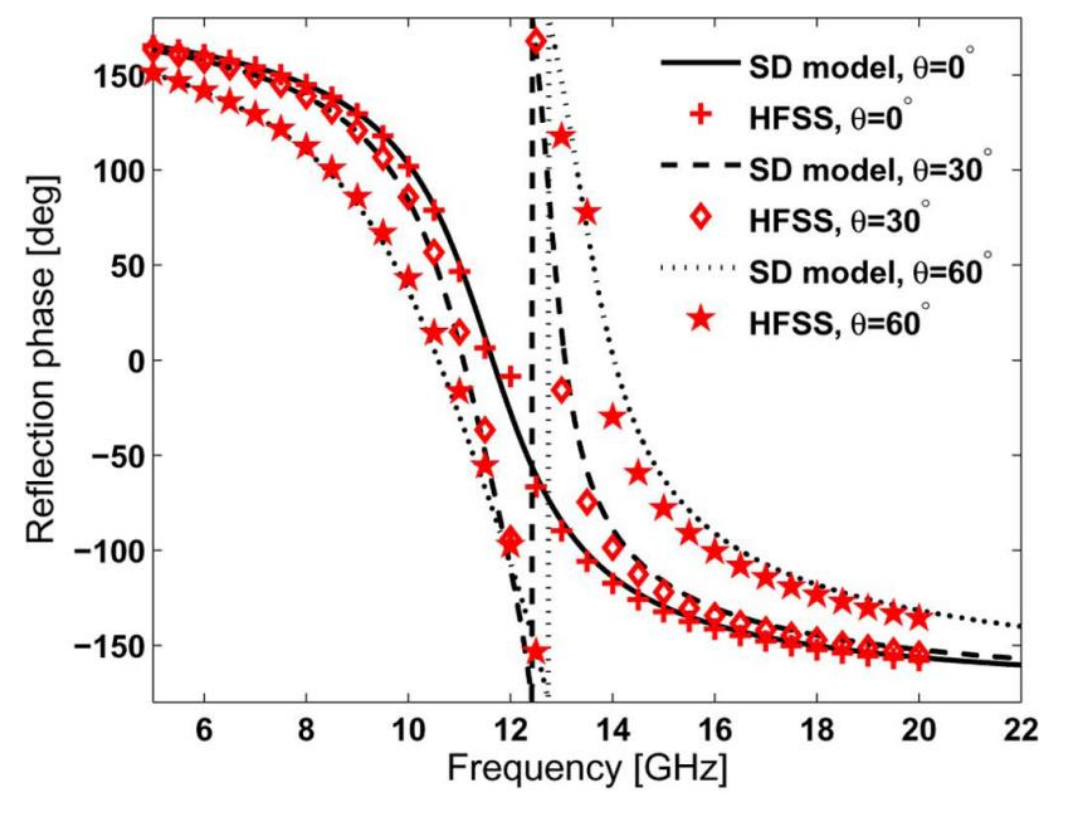
## Introduction – Mushroom-Type HIS



Additional boundary condition for the “microscopic” current at the via-ground plane connection ( $y=0^-$ ) and via-patch connection ( $y=-h^+$ ):

$$\frac{dI(y)}{dy} \Big|_{y=0^-} = 0 \quad \text{Silveirinha et al., New J. Phys., 10, 2008}$$

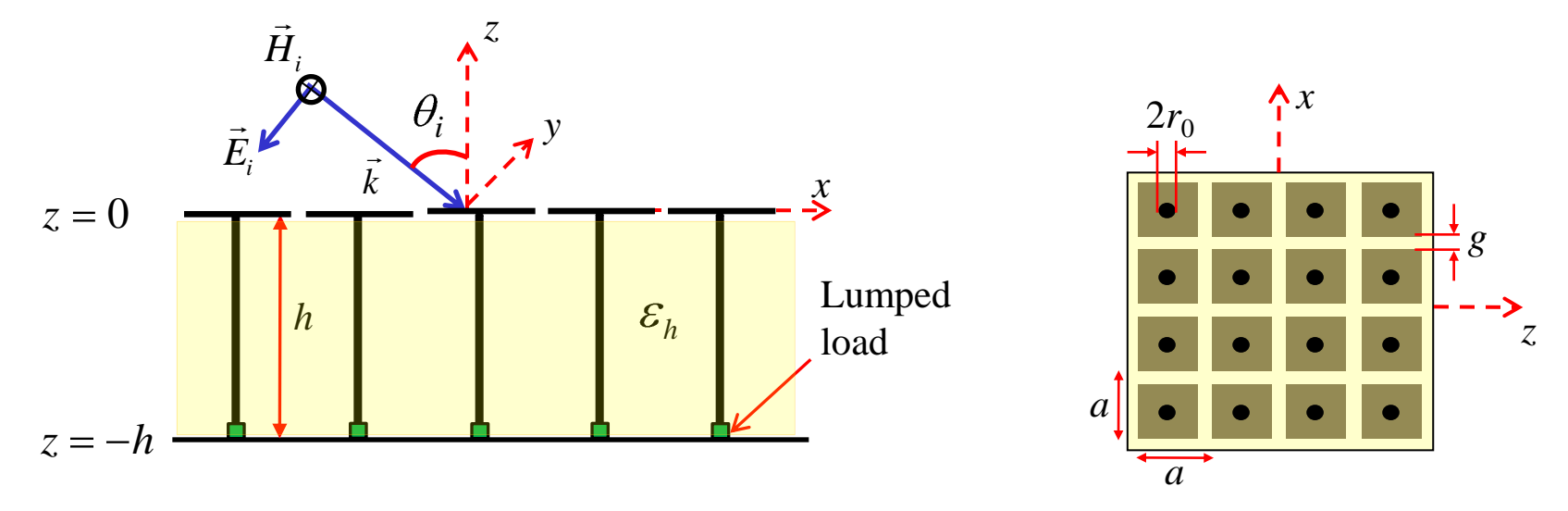
## Reflection Characteristics and Natural Modes



- ✓ Reflection phase characteristics and natural modes (surface waves and leaky waves) are accurately predicted by the homogenization model.
- ✓ The presence of the patch grid significantly reduces the spatial dispersion (SD) effects.

O. Luukkonen et al., IEEE Trans. Microwave Theory Tech., 57, Nov. 2009  
A. B. Yakovlev et al., IEEE Trans. Microwave Theory Tech., 57, Nov. 2009

## Mushroom-Type HIS with Loaded Vias



## Nonlocal Homogenization model

Wire medium slab is treated as an uniaxial continuous material characterized by tensor effective permittivity

$$\frac{\bar{\bar{\epsilon}}}{\epsilon_0} = \epsilon_h \left( \bar{\bar{I}}_t + \left( 1 - \frac{k_p^2}{k_h^2 - k_z^2} \right) \hat{z}\hat{z} \right) \quad k_p = \sqrt{\epsilon_0 \pi / a^2} \log \left( \frac{2}{\epsilon_0 r_0} \left( \frac{1}{\epsilon_0} - r_0 \right) \right)$$

Plasma wavenumber

TM-polarized plane wave excites TEM and TM modes in the wire medium slab

$$\eta_0 H_y = A_{TM}^+ e^{\gamma_{TM} z} + A_{TM}^- e^{-\gamma_{TM} z} + B_{TM}^+ e^{\gamma_{TM} z} + B_{TM}^- e^{-\gamma_{TM} z}$$

$$E_x = \frac{j}{\epsilon_h k_0} \left[ \gamma_{TM} \left( A_{TM}^+ e^{\gamma_{TM} z} - A_{TM}^- e^{-\gamma_{TM} z} \right) + \gamma_{TM} \left( B_{TM}^+ e^{\gamma_{TM} z} - B_{TM}^- e^{-\gamma_{TM} z} \right) \right]$$

$$\gamma_{TEM} = j k_0 \sqrt{\epsilon_h} \quad \gamma_{TM} = \sqrt{k_p^2 + k_x^2 - k_0^2 \epsilon_h}$$

Tangential electrical and magnetic fields are related via the sheet impedance at the air patch interface  $z=0$

## Nonlocal Homogenization Model

- Generalized additional boundary condition at the via-to-patch connection,  $z=0^-$ :

$$\frac{dI(z)}{dz} + \left( \frac{C}{C_{patch}} \right) I(z) = 0$$

In terms of field components

$$\left( k_0 \epsilon_h \frac{dE_z}{dz} + k_x \eta_0 \frac{dH_y}{dz} \right) + \left( \frac{C}{C_{patch}} \right) \left( \epsilon_0 \epsilon_h E_z + k_x \eta_0 H_y \right) = 0$$

- Generalized additional boundary condition for the lumped load at the via-to-ground connection,  $z=-h^+$ :

$$\frac{dI(z)}{dz} - j\omega C Z_{Load} I(z) = 0 \quad Z_{Load} \rightarrow \text{Load impedance}$$

In terms of field components

$$\left( k_0 \epsilon_h \frac{dE_z}{dz} + k_x \eta_0 \frac{dH_y}{dz} \right) - j\omega C Z_{Load} \left( \epsilon_0 \epsilon_h E_z + k_x \eta_0 H_y \right) = 0$$

S. I. Maslovski et al., New J. Phys., 12, 113047, 2010

$$Z_L = j\omega L_{par} + \frac{1}{j\omega C_{par} + C_{Load}}$$

$L_{par}$  and  $C_{par}$  are the correction terms, due to non-uniformity in the charge and current distribution by inserting a load in the wire

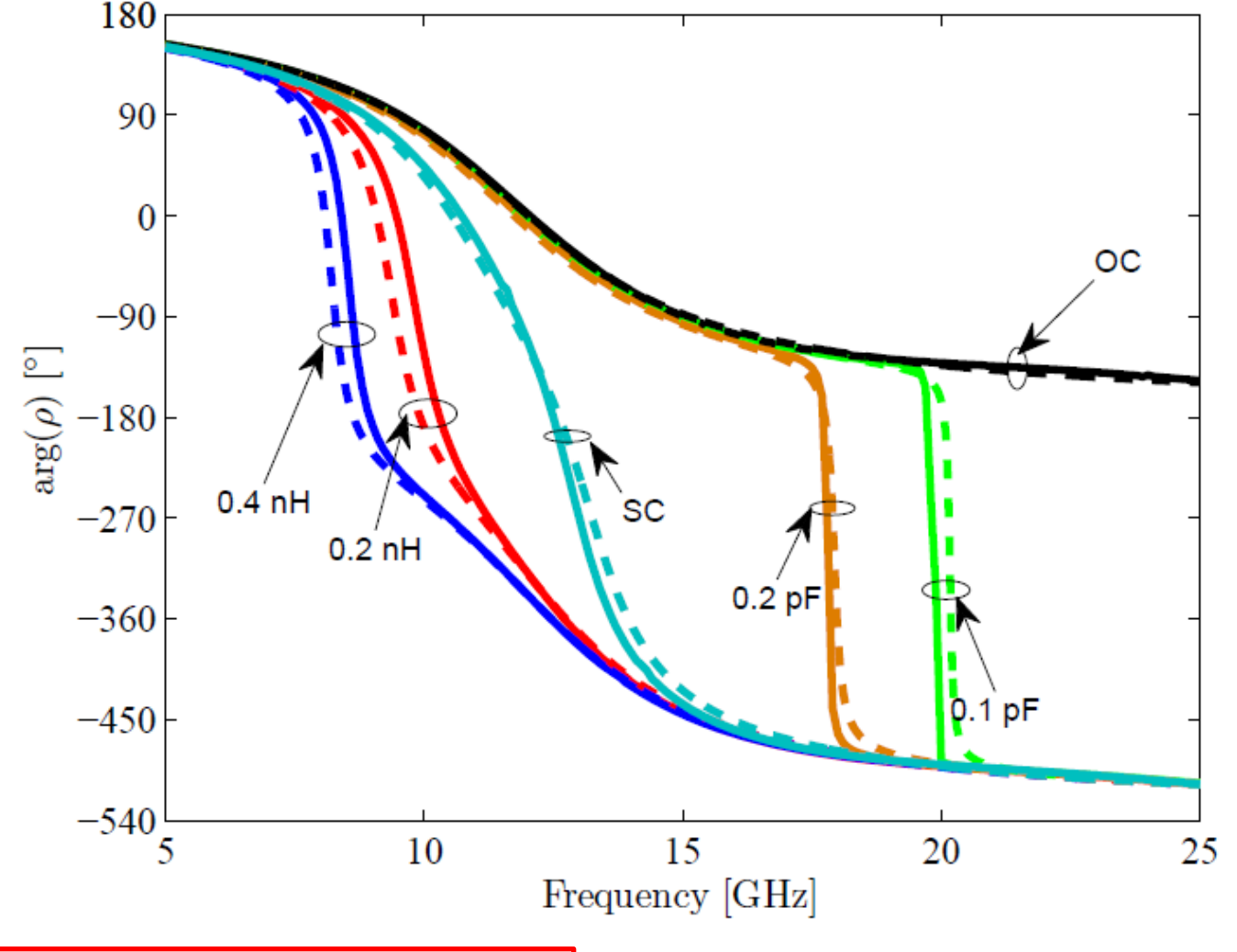
## Reflection Coefficient

$$\rho = \frac{j\omega \epsilon_0 - \gamma_0 Y_g \bar{K} - j\omega \epsilon_0 \gamma_0 M}{j\omega \epsilon_0 - \gamma_0 Y_g \bar{K} + j\omega \epsilon_0 \gamma_0 M}$$

$$K = \gamma_{TM} \sinh \left( \gamma_{TM} h \right) \cos \left( \gamma_{TEM} h \right) + j \gamma_{TEM} \sin \left( \gamma_{TEM} h \right) \left( \frac{\epsilon_h}{\epsilon_{zz}^{TM}} - 1 \right) \cosh \left( \gamma_{TM} h \right) + \frac{\epsilon_h \gamma_{TM}}{\epsilon_{zz}^{TM} j\omega C Z_L} \sinh \left( \gamma_{TM} h \right)$$

$$M = 2 \left( \epsilon_h - \epsilon_{zz}^{TM} \right) \cosh \left( \gamma_{TM} h \right) \left( \frac{j\epsilon_h k_{TEM}}{\omega C Z_L} \sin \left( \gamma_{TEM} h \right) + \left( \epsilon_h \left( \frac{\epsilon_h}{\epsilon_{zz}^{TM}} - 2 \right) + 2\epsilon_{zz}^{TM} \right) \cos \left( \gamma_{TEM} h \right) \right) + \left( \epsilon_h - \epsilon_{zz}^{TM} \right) \sinh \left( \gamma_{TM} h \right) \left( \frac{\gamma_{TEM}}{\gamma_{TM}} + \frac{\gamma_{TM}}{\gamma_{TEM}} \right) j \sin \left( \gamma_{TEM} h \right) + \frac{\epsilon_h \gamma_{TM}}{j\omega C Z_L \epsilon_{zz}^{TM}} \cos \left( \gamma_{TEM} h \right)$$

## Reflection Characteristics



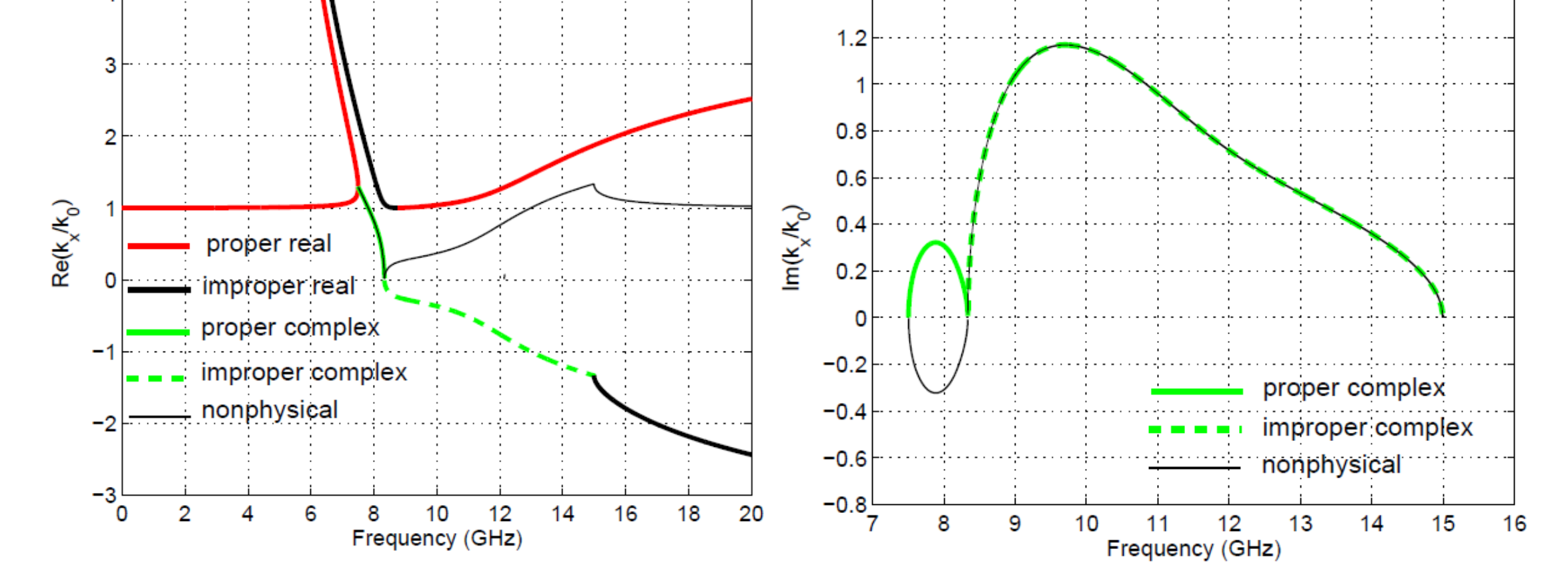
Thickness ( $h$ ) = 1 mm  
Period ( $a$ ) = 2 mm  
Gap ( $g$ ) = 0.2 mm,  
Permittivity  $\epsilon_h = 10.2$ ,

— Analytical  
- - - HFSS

- ✓ The load is connected to the ground plane through a gap of 0.1 mm, by curve fitting, the correction terms are  $L_{par} = 0.02$  nH and  $C_{par} = 0.06$  pF.

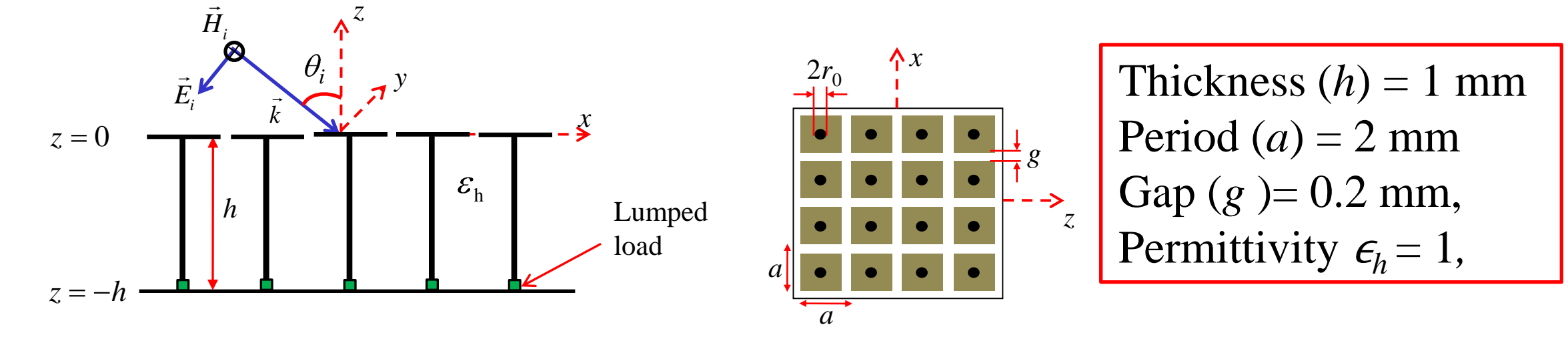
- ✓ Reflection phase characteristics depend strongly on the value and the type of load.
- ✓ For an increase in the value of the inductive loads, we have a decrease in the plasma frequency and reduction in SD effects.

## Dispersion Behavior for 0.4 nH Load



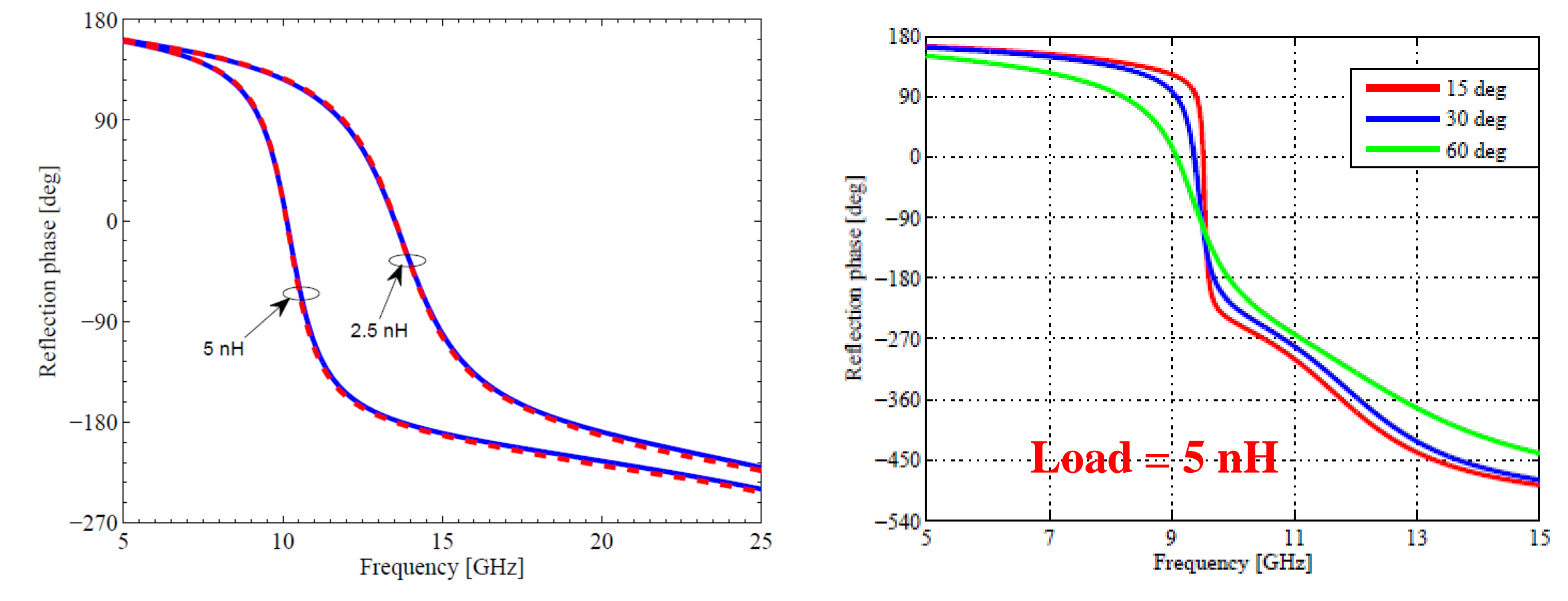
- ✓ The dispersion behavior shifts to lower frequency when compared to the structure without loads.

## Ultra Thin HIS



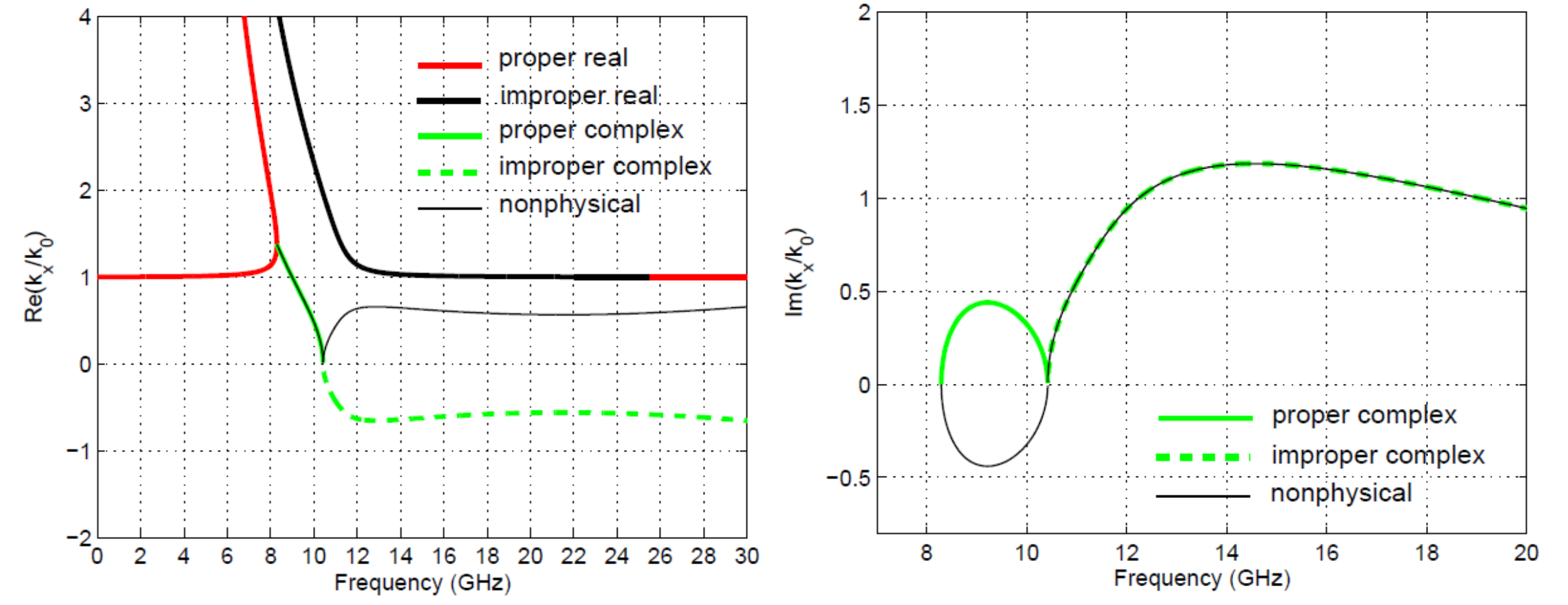
Thickness ( $h$ ) = 1 mm  
Period ( $a$ ) = 2 mm  
Gap ( $g$ ) = 0.2 mm,  
Permittivity  $\epsilon_h = 1$ ,

## Reflection Characteristics



- ✓ The resonance frequency is shifted to a much lower value, when compared to the structure without loads.
- ✓ The effects of the parasitic capacitance and parasitic inductance in the air filled structure are negligible.
- ✓ Electrical thickness of the structure at the operating frequencies for 5 nH load is  $\approx \lambda_0/30$

## Dispersion Behavior for 5 nH Load



- ✓ Exhibits a wide stop-band for surface waves, 8.29 GHz – 25.51 GHz.
- ✓ 73% reduction in the plasma frequency when compared to the structure without loads.

## Conclusion

- The reflection characteristics of the mushroom-type surface with loaded vias can be accurately predicted by the homogenization model.
- The reflection phase depends strongly on the value and the type of load. With an increase in the value of the inductive load, we have a decrease in the plasma frequency with a reduction in SD effects.
- Ultra thin structure exhibits wide stop-band for surface waves.
- The proposed concept of lumped loads can be used as EBG substrates in ridge waveguides and in the design of ultra-thin absorbers.